

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE

2SC5171

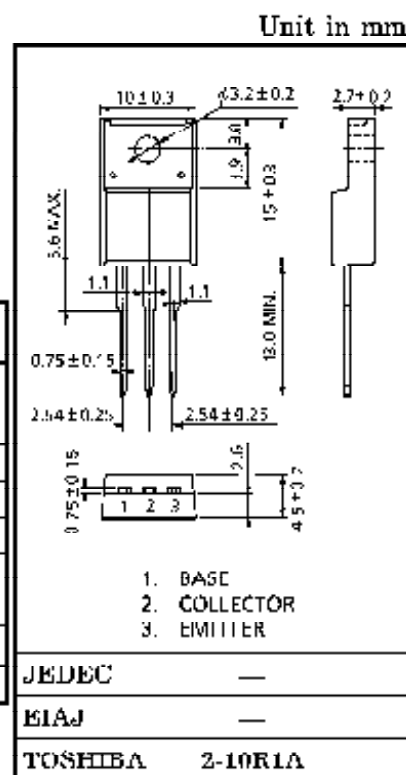
POWER AMPLIFIER APPLICATIONS

DRIVER STAGE AMPLIFIER APPLICATIONS

- High Transition Frequency : $f_T=200\text{MHz}$ (Typ.)
- Complementary to 2SA1930

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CB0}	180	V
Collector-Emitter Voltage	V_{CE0}	180	V
Emitter-Base Voltage	V_{EB0}	5	V
Collector Current	I_C	2	A
Base Current	I_B	1	A
Collector Power Dissipation	P_C	2.0	W
		20	
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-55\sim 150$	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$)

Weight : 1.7g (Typ.)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=180\text{V}$, $I_E=0$	—	—	5.0	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5\text{V}$, $I_C=0$	—	—	5.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10\text{mA}$, $I_B=0$	180	—	—	V
DC Current Gain	$h_{FE(1)}$	$V_{CE}=5\text{V}$, $I_C=0.1\text{A}$	100	—	320	
	$h_{FE(2)}$	$V_{CE}=5\text{V}$, $I_C=1\text{A}$	50	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1\text{A}$, $I_B=0.1\text{A}$	—	0.16	1.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=5\text{V}$, $I_C=1\text{A}$	—	0.68	1.5	V
Transition Frequency	f_T	$V_{CE}=5\text{V}$, $I_C=0.3\text{A}$	—	200	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$	—	16	—	pF

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